MBRS1100T3G, **SBRS81100T3G**, MBRS190T3G, **SBRS8190T3G**

Schottky Power Rectifier

Surface Mount Power Package

Schottky Power Rectifiers employ the use of the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system. These state-of-the-art devices have the following features:

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- High Blocking Voltage 100 Volts
- 175°C Operating Junction Temperature
- Guardring for Stress Protection
- AEC-Q101 Qualified and PPAP Capable
- SBRS8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm Tape and Reel, 2,500 units per reel
- Cathode Polarity Band



ON Semiconductor®

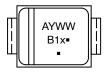
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SCHOTTKY BARRIER RECTIFIER 1.0 AMPERE 90, 100 VOLTS



SMB CASE 403A

MARKING DIAGRAM



B1 = Device Code

= C for MBRS1100T3 9 for MBRS190T3

= Assembly Location

= Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MBRS1100T3G, SBRS81100T3G, MBRS190T3G, SBRS8190T3G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage MBRS190T3 MBRS1100T3	V _{RRM} V _{RWM} V _R	90 100	V	
Average Rectified Forward Current $T_L = 163^{\circ}C$ $T_L = 148^{\circ}C$	I _{F(AV)}	1.0 2.0	А	
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	50	А	
Operating Junction Temperature (Note 1)	T _J	-65 to +175	°C	
Voltage Rate of Change	dv/dt	10	V/ns	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance – Junction–to–Lead (T _L = 25°C)	$R_{ hetaJL}$	22	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) (i _F = 1.0 A, T _J = 25°C)	V _F	0.75	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, TJ = 25°C) (Rated dc Voltage, T _J = 100°C)	I _R	0.5 5.0	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]	
MBRS1100T3G	B1C	SMB (Pb-Free)	2500 / Tape & Reel	
SBRS81100T3G	B1C	SMB (Pb-Free)	2500 / Tape & Reel	
MBRS190T3G	B19	SMB (Pb-Free)	2500 / Tape & Reel	
SBRS8190T3G	B19	SMB (Pb-Free)	2500 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

^{2.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

MBRS1100T3G, SBRS81100T3G, MBRS190T3G, SBRS8190T3G

TYPICAL ELECTRICAL CHARACTERISTICS

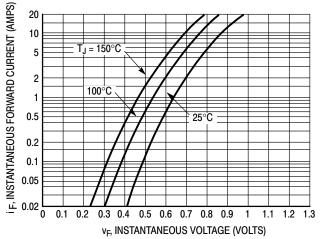


Figure 1. Typical Forward Voltage

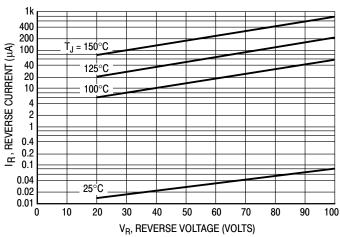


Figure 2. Typical Reverse Current*

*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if $V_{\rm R}$ is sufficient below rated $V_{\rm R}$.

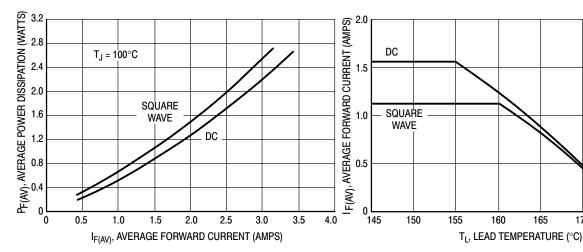


Figure 3. Power Dissipation

Figure 4. Current Derating, Lead

175

180

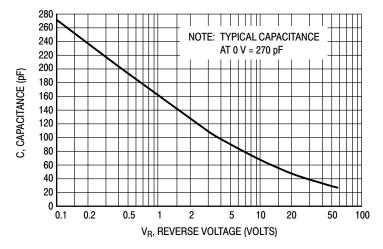
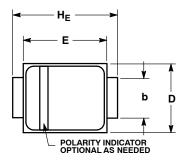


Figure 5. Typical Capacitance

MBRS1100T3G, SBRS81100T3G, MBRS190T3G, SBRS8190T3G

PACKAGE DIMENSIONS

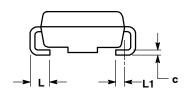
SMB CASE 403A-03 **ISSUE J**

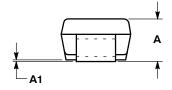




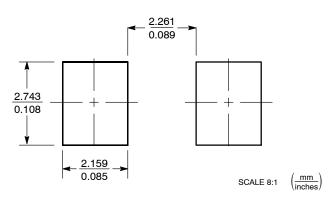
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L1.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.95	2.30	2.47	0.077	0.091	0.097
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.96	2.03	2.20	0.077	0.080	0.087
С	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
HE	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1	0.51 REF			0.020 REF		





SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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